LARGE BANDWIDTH DUAL POLARIZED CIRCULAR SLOT ANTENNA.

APPLICATION TO AN ARRAY IN KU BAND.

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I. INTRODUCTION. A dual polarization is useful when, for instance the target diffraction matrix analysis is to be known. For mobile equipments having antenna gains in the range 20 dBi, printed technology appears to offer a right solution. The large bandwidth elementary radiating source is a circular slot acting at the second resonance. The characteristics of an isolated large bandwidth circular slot directional elementary source partially embedded in a dielectric substrate are deduced from those of an equivalent circular loop with sinusoidal current distribution when Babinet's principle is applied. The influence of the width of the slot upon the bandwidth is taken into account. Then a reflector is taken into account using the electrical image principle to give a directional radiation. The central metallic disc is fed at two orthogonal points. Coupling between the two feed points is partly due to the presence of higher modes. An application to an array in Ku band is given.

II. THE ISOLATED CIRCULAR LOOP IN AIR MEDIUM. In a first recent paper [1] we deduced the theoretical radiation resistance of an isolated slot ring resonator in air medium from that of an equivalent plane circular loop with constant current distribution. The radiation resistance $(R_r)_R$ for a thin ring is given by the expression :

$$(R_{r})_{R} = \frac{\pi}{2} \sqrt{\mu_{o}/\epsilon_{o}} x^{4} \sum_{n=0}^{+\infty} \frac{(-1)^{n} x^{2n}}{(n+2)(n+1)n!(n+\frac{3}{2})}$$
(1)

where 2b and 2a are respectively the diameters of the loop and its constant circular cross section. n was an integer, $x=2\pi b/\lambda$, and a<
b</ri>

when the circumference of the loop is less than 0.8 λ_0 the constant current radiation resistance agrees quite well with that of the sinusoidal distribution. A first purpose was to express the radiation resistance of a circular loop in air medium, when its thickness parameter, defined by $\Omega_R = 2\log_e{(2\pi b/a)}$ (2), is taken into account : [2]. The radiation admittance $(Y_r)_R$ is given by [3]:

[3]:
$$(Y_r)_R = -\frac{j}{\pi} \sqrt{\varepsilon} \sqrt{\mu_0} \left[\frac{1}{a_0} + 2 \sum_{n=1}^{\infty} \frac{1}{a_n} \right] = (G_r)_R + j (B_r)_R$$

$$(3) \text{ with } a_0 = k_0 b K_1,$$

$$a_n = \frac{k_0 b}{2} (K_{n+1} + K_{n-1}) - \frac{n^2}{k_0 b} K_n \text{ and } K_0 = \frac{1}{\pi} \log_e \frac{8b}{a} - \frac{1}{2} \int_0^{2k_0 b} [\Omega_0(x) + j J_0(x)] dx$$

$$K_n = \frac{1}{\pi} \left[\frac{1}{2} \int_0^{\infty} (n \frac{a}{b}) \int_0^{\infty} (n \frac{a}{b}) + \log_e (4n) + \gamma - 2 \sum_{m=0}^{n-1} (2m+1)^{-1} \right] - \frac{1}{2} \int_0^{2k_0 b} [\Omega_{2n}(x) + j J_{2n}(x)] dx$$
where $\frac{2\pi}{a_0} \int_0^{\infty} (n \frac{a}{b}) \int_0^{\infty} (n \frac{a}{b}) + \log_e (4n) + \gamma - 2 \sum_{m=0}^{n-1} (2m+1)^{-1} \right] - \frac{1}{2} \int_0^{2k_0 b} [\Omega_{2n}(x) + j J_{2n}(x)] dx$

where \mathcal{H}_0 and \mathcal{Y}_0 are the modified Bessel functions of the second and first kinds, \mathcal{I}_{2n} is the Bessel function of the first kind, Ω_{2n} is the Lommel-Weber function, γ is the Euler constant and k is the free-space wavenumber. n is an integer. We have : $\Omega_{2n}(\mathbf{x}) = \frac{1}{\pi} \int_0^\pi \sin(\mathbf{x} \sin\theta - 2n\theta) \, \mathrm{d}\theta$

$$\mathcal{J}_{O}(x) = \frac{1}{\pi} \int_{O}^{\pi} \cosh(z \cos \theta) d\theta. \quad \mathcal{K}_{O}(z) = -\frac{1}{\pi} \int_{O}^{\pi} e^{\pm z \cos \theta} \{ \gamma + \log_{\theta}(2z \sin^{2}\theta) \} d\theta$$

$$\mathcal{J}_{2n}(x) = \frac{1}{\pi} \int_{O}^{\pi} \cos[x \sin \theta - 2n\theta] d\theta$$

At the second resonance that is for k b near 1 we put :

$$k_0 = x_r$$
 for $B_{res} = 0$ and $(R_r)_R = 1/Y_{res}$.

The table I shows the x parameter values and the radiation resistance (R_) related to the ring or circular loop operating at the second resonance

$\Omega_{\mathbb{R}}$	20	18	16	14	13	12	11	10
$k_ob = x_r$	1.034	1.039	1.048	1.061	1.071	1.086	1.110	1.162
(R _r) _R (ohms)	138	139	140	142	144	148	154	173
B %	6.8	7.7	9.5	11.3	14.0	15.5	19.6	24.0

Table I

The bandwidth B expressed in percent for a V.S.W.R. \leqslant 2 is given in Table I. The bandwidth B increases with the ring thickness that is when $\Omega_{\rm R}$ decreases.

The current distribution along the loop is given by : [3]
$$I(\Phi) = I_0 + 2 \sum_{n=1}^{\infty} I_n cosn\Phi$$
 (4) with $I_n = \frac{-j}{\pi} \frac{V_0}{a_n} \sqrt{\epsilon_0/\mu_0}$

V is the potential which is applied across a gap in the ring at Φ = 0. We deduced from (3) and (4) the ratio $\frac{\left|\underline{I}\underline{M}\right|}{I_{\overline{M}}} = \frac{\left|\underline{I}\left(\Phi\right)\right|_{Max}}{\left|\underline{I}\left(\Phi_{1}\right)\right|}, \quad \Phi_{1} \text{ being the angle } \Phi \text{ for which } \frac{\left|\underline{I}\left(\Phi\right)\right|}{V} \text{ is minimum.}$ The phase shift $\Delta\Phi$ between I(Φ =180°) and I(ϕ =0) is of main importance. Table II gives these parameters in terms of np.

Ω_{R}	20	18	16	14	13	12	11	10
φ ₁ (degrees)	90	91	91	91	91	92	93	97
$\left \frac{\mathbf{I}_{M}}{\mathbf{I}_{m}} \right $ (dB)	23.3	22.0	20.7	19.2	18.2	17.1	15.8	14.0
ΔΦ (degrees)	181	182	183	184	185.5	188	192	201

Table II

The current distribution in amplitude and phase along the ring shows that there is a transverse main beam. From the table II we can deduce that the purety of polarization becomes better as the parameter Ω_{R} increases, that is as the ring thickness decreases. The ideal case would be given by : $\Delta \varphi = 180^{\circ}, \qquad \varphi_{1} = 90^{\circ} \quad \text{and} \quad \left| \frac{\textbf{I}_{M}}{\textbf{I}_{m}} \right| = +\infty.$

$$\Delta \phi = 180^{\circ}$$
, $\phi_1 = 90^{\circ}$ and $\left| \frac{I_M}{I_m} \right| = +\infty$.

These results are confirmed, when the radiated electromagnetic far-field, calculated from the following expressions, is taken into account :

with :
$$\begin{split} \stackrel{\rightarrow}{E}(\phi,\theta) &= E_{\dot{\phi}}(\phi,\theta) \stackrel{\rightarrow}{\phi}^{k} + E_{\dot{\theta}}(\phi,\theta) \stackrel{\rightarrow}{\theta}^{k} \\ &= E_{\dot{\phi}}(\phi,\theta) = -\sqrt{\mu_{\dot{\phi}}/\epsilon_{\dot{o}}} \psi \cot g\theta \sum_{n=1}^{\infty} j^{n} n \ I_{n} \sin(n\phi) . J_{n}(k_{\dot{o}}b \sin \theta) \\ &= E_{\dot{\phi}}(\phi,\theta) = \sqrt{\mu_{\dot{\phi}}/\epsilon_{\dot{o}}} \frac{k_{\dot{o}}b}{2} \psi \{I_{\dot{o}}J_{1}(k_{\dot{o}}b \sin \theta) + \sum_{n=1}^{\infty} I_{n} \ j^{n} \cos(n\phi) \times \\ &= [J_{n+1}(k_{\dot{o}}b \sin \theta) - J_{n-1}(k_{\dot{o}}b \sin \theta)] \} \end{split}$$

 ψ is the free space Green function.

In H plane $(\phi = 0, \theta)$ the cross polarization is given by :

$$\tau(\theta) = E_{\theta}(\phi = 0, \theta)/E_{\Phi}(\phi = 0, \theta)$$

In E plane $(\phi=\pi/2,\theta)$ the cross polarization is given by :

$$\tau(\theta) = E_{\phi}(\phi = \pi/2, \theta)/E_{\theta}(\phi = \pi/2, \theta)$$

The table III and IV gives respectively for $\Omega_R=20$ and 10 the cross polarization in axis : $\tau=\tau(\theta=0)$ in dB and the 3dB beamwidth (in degrees) in "E" and "H" planes in terms of frequency around the second resonance. In each case the cross-polarization level runs through a minimum all the more as the frequency is near the resonance and the ring in thinner ($\Omega_{\rm p}$ =20)

	τ_	θ _{3dB} (degrees)			
×	(dB)	E plane	H plane		
0.9	-16.8	84	> 180		
0.99	-23	82	144		
1.028	-26	82	134		
1.07	-24	82	122		
1.12	-19.5	80	112		
1.20	-14.5	78	110		

 $\Omega_{R} = 20$

Table III

×	το	θ _{3dB} (degrees)				
	(dB)	E plane	H plane			
0.93	-14.9	84	> 180			
0.95	-15.5	82	> 180			
1.03	-17.2	82	142			
1.059	-17.3	82	132			
1.09	-17.2	82	124			
1.12	-16.7	81	118			
1.16	-15.8	80	108			
1.19	-15	80	104			
1.22	-14.1	78	98			
1.32	-11.3	77	84			

 $\Omega_{\rm p}$ = 10 Table IV

III. THE ISOLATED CIRCULAR SLOT IN AIR MEDIUM. The radiation impedance (Z_r)_S of the circular slot can be deduced by applying Babinet's principle as (fig. 1): $(Z_r)_S = \frac{1}{4} (Y_r)_R \cdot \frac{\mu_O}{\epsilon_O} \cdot \frac{1}{\epsilon_O}$ (5) with $\Omega_S = 2\log_e 4\pi (\frac{r_2 + r_1}{r_2 - r_1})$

This model, deduced by duality, has an identical bandwidth than the ring one's. At the second resonance we obtained from Table I and for ϵ = 1 the results shown in Table V.

$\Omega_{\mathbf{S}}$	20	18	16	14	13	12	11	10
$\frac{\pi(r_1+r_2)}{\lambda_0}$	1.034	1.039	1.048	1.061	1.071	1.086	1.110	1.162
(R _r) _s , Ω	257	256	254	250	247	240	231	205
B %	6.8	7.7	9.5	11.3	14.0	15.5	19.6	24.0

Table V

Results shown in Tables II, III and IV are valid when ring currents are changed into electric field across the slot. In table VI we deduced a correct agreement between experiments and theory.

Model	Ωs	experimental (R _r) _S [7]	theory (R _r) _S Table V
$r_1 = 77$ $r_2 = 82$	12	235 ± 10	240
$r_1 = 77$ $r_2 = 79,5$	13,3	232 ± 10	247

Table VI

IV. THE ISOLATED CIRCULAR SLOT PARTIALLY EMBEDDED IN A DIELECTRIC SHEET. At resonance, that is for $x_r = (k)_r b = (k_0) \sqrt{\epsilon_e} b$, we can write for the radia-

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, we can write for the tion resistance [2]:
$$(R_r)^{\epsilon_e} = (R_r)_S \cdot \epsilon_e \cdot \frac{1 - \frac{1}{5} + \frac{1}{28} - \frac{1}{180} + \frac{1}{1320} \cdot \dots}{1 - \frac{1}{5\epsilon_e} + \frac{1}{28\epsilon_e^2} - \frac{1}{180\epsilon_e^3} + \frac{1}{1320\epsilon_e^4} \cdot \dots}$$
(6)
The bandwidth B is divided by $\sqrt{\epsilon_e}$ as an usual result [5]. The equiv

The bandwidth B_o is divided by $\sqrt{\epsilon_e}$ as an usual result [5]. The equivalent relative permittivity ϵ_r is deduced from the dielectric thickness d and relative permittivity ϵ_r knowledge.

In table VII we compare theoretical results given by our method and transmission-line model analysis [6], with some experimental ones.

Model	r ₁ (mm)	r ₂ (mm)	d (mm)	f _r (GHz)	εr	ε _e	(R _r)s (Ω) from (3) and (6)	(R _r) _S (Ω) theory [6]	(R _r)s (Ω) experiments [6]
1	4	4.14	0.78	10	2.17	1.38	325	330	307
2	18.45	18.75	0.635	1.5	10.2	2.93	653	606	575
3	30.48	33.02	6.35	0.72	12	4.36	891	860	

Table VII

V. THE CIRCULAR SLOT DIRECTIONAL ANTENNA. We added reflector parallel to the slot at a distance d, and filled with a dielectric substrate. Then the slot input radiation resistance (R) $^{\epsilon}_{r}$ can be written as [2]:

$$(R_r)_S^{\epsilon_e,d} = (R_r)_S^{\epsilon_e} \boxed{1+3 \frac{\cos 2kd}{(2kd)^2} - 3 \frac{\sin 2kd}{(2kd)^3}}$$
 (7) with $k = k_0 \sqrt{\epsilon_e}$.

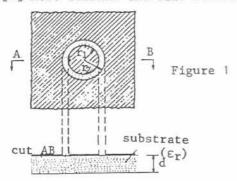
We studied a model with the following parameters: r₁=3.2mm, r₂=3.7mm, ϵ =2.17 and d = 3.2mm. As d >> r₂-r₁: ϵ_e =(1+ ϵ_r)/2. We deduced Ω_s = 10.31 from the table V: B # B $/\sqrt{\epsilon_e}$ 19%, and with the table V, (6), (7): (R) ϵ_e 0 = 144 Ω . The experimental values are 20 % and 125 ohms.

VI. APPLICATION TO AN ARRAY IN Ku BAND. At the second resonance the circular slot diameter D is such that : 0.33 $\leq \frac{D}{(\lambda_{0})r} \sqrt{\epsilon_{e}} \leq$ 0.37. It has independent feed points for each polarization. Coupling between the feed points is partly due to the presence of higher order modes, which were reduced by means of shorting pins as indicated in fig. 2. The coupling was decreased until -20 dB. Constant spacings between circular slots along lines and columns, equal to 0.68 λ and 0.80 λ are suitable to obtain correct radiation patterns, and to reduce the complexity of both corporate feeds which can be laid on the same triplate. Theoretical results are in good agreement with experiments.

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REFERENCES.

- [1] G. DUBOST. Elect. Letters, vol. 23, n° 18, pp. 928-930, August 1987.
- [2] G. DUBOST, Elect. Letters, vol. 24, n° 23, pp. 1449-1450, Nov. 1988.
- [3] R.W.P. KING "Antennas in Matter: fundamentals, theory and applications" (MIT Press, 1981).
- [4] G. DUBOST, A. BIZOUARD. Tev. Techn. Thomson-C.S.F. 1979, 11, pp.577-643
- [5] G. DUBOST. Ann. Télécomm., 42, n° 9-10, 1987, p. 588 à 605.
- [6] T. DUSSEUX. Thèse Docteur Ingénieur, Univ. Rennes I, Mai 1987.
- [7] K.D. STEPHAN and all. I.E.E.E. Trans. 1983, MTT 31, p. 164.



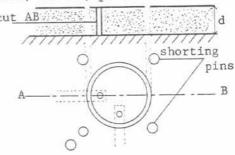


Figure 2